

AlGaAs Infrared Laser Diode

ADL-85Y51TU

6-2D-LD85-029_Rev.00

850nm 250mW High Power Operation

Features

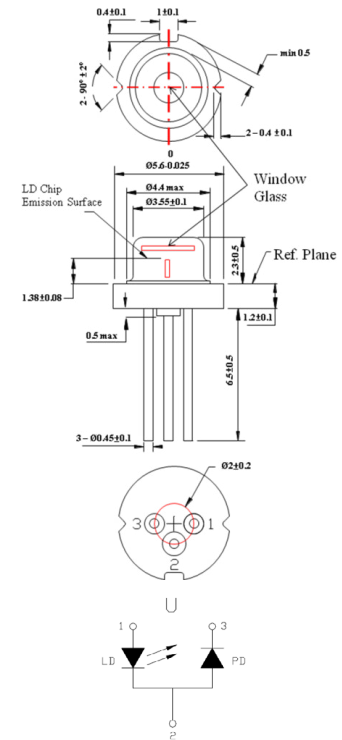
- 250mW kink free power
- Small package: Ø5.6mm
- Small far field angle
- High reliability/ Low astigmatism/ High efficiency

Applications

- Light source for sensing device
- LIDAR (light detection & ranging)
- 3D Sensing with Laser
- Illumination/ Medical application/ Imaging

Absolute maximum ratings

Parameter	Symbol	Condition	Rating	Unit
Light output power	P _O	CW	270	mW
Reverse voltage (LD)	V _{RL}	-	2	V
Case temperature	T _C	-	-10~+60	°C
Storage temperature	T _S	-	-40~+85	°C



Electrical and optical characteristics (T_c=25 °C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Peak wavelength	λ	840	850	860	nm	P _O =250mW
Threshold current	I _{th}	-	65	90	mA	
Operating current	I _{op}	-	310	360	mA	
Operating voltage	V _{op}	-	1.9	2.4	V	
Differential efficiency	η	0.90	1.00	-	mW/mA	P _O =200-250mW
Monitor current	I _m	0.5	1.1	1.8	mA	P _O =250mW, V _{RD} =5V
Parallel divergence angle	θ	6	8	13	deg.	P _O =250mW
Perpendicular divergence angle	θ _⊥	12	17	22	deg.	
Parallel FFP deviation angle	Δθ	-3	0	+3	deg.	
Perpendicular FFP deviation angle	Δθ _⊥	-3	0	+3	deg.	
Emission point accuracy	ΔxΔyΔz	-80	0	+80	um	

* Sufficient heat dissipation is required for CW operation.

● Precautions

- Do not operate the device above maximum ratings. Doing so may cause unexpected and permanent damage to the device.
- Take precautions to avoid electrostatic discharge and/or momentary power spikes. A change in the characteristics of the laser or premature failure may result.
- Proper heat sinking of the device assures stability and lifetime. Always ensure that maximum operating temperatures are not exceeded.
- Observing visible or invisible laser beams with the human eye directly, or indirectly, can cause permanent damage. Use a camera to observe the laser.
- No laser device should be used in any application or situation where life or property is at risk in event of device failure.
- Specifications are subject to change without notice. Ensure that you have the latest specification by contacting us prior to purchase or use of the product

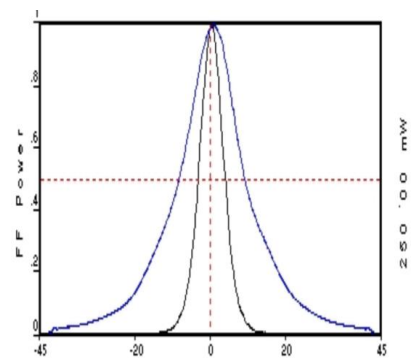
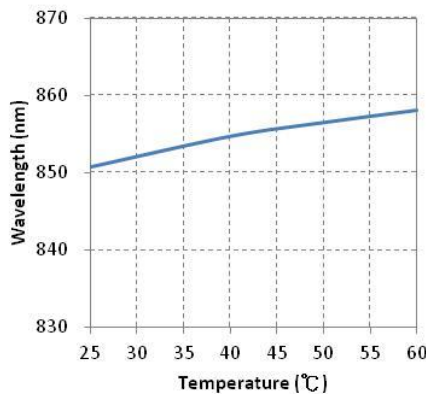
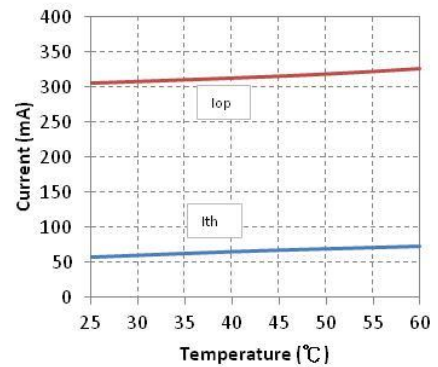
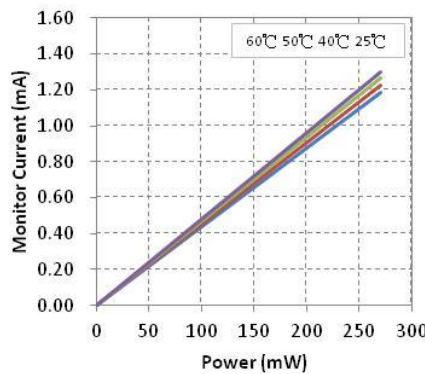
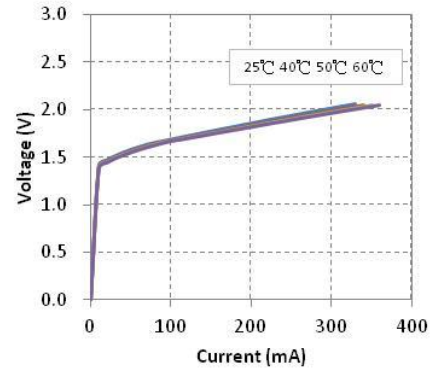
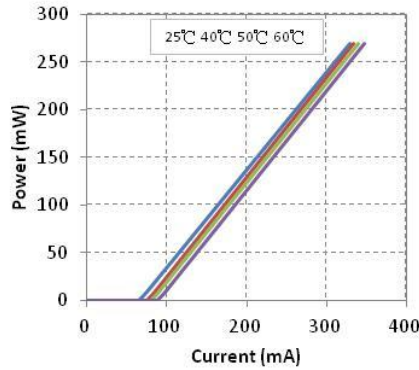
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